

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Taiwan Semiconductor

N-Channel Power MOSFET

30V, 62A, 6mΩ

FEATURES

- Low R_{DS(ON)} to minimize conductive Loss
- Low gate charge for fast power switching
- 100% UIS and R_g tested
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

PRODUCT SUMMARY				
PARAMETER		VALUE	UNIT	
$V_{ t DS}$		30	V	
R _{DS(on)} (max)	$V_{GS} = 10V$	6	0	
	$V_{GS} = 4.5V$	9	mΩ	
Q_g		12.9	nC	

Pb



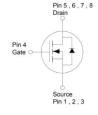


APPLICATIONS

- DC-DC Converters
- Battery Power Management
- Oring FET/Load Switch

PDFN33





Notes: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Courset (Note 1)	$T_C = 25^{\circ}C$,	62	^	
Continuous Drain Current (Note 1)	$T_A = 25^{\circ}C$	I _D	15	А	
Pulsed Drain Current (Note 1)		I _{DM}	248	Α	
Single Pulse Avalanche Current (Note 2)		I _{AS}	29	Α	
Single Pulse Avalanche Energy (Note 2)		E _{AS}	42	mJ	
Total Bawar Dissination	$T_C = 25^{\circ}C$	D	40	W	
Total Power Dissipation	$T_C = 125$ °C	P_{D}	8	VV	
Total Power Dissipation	$T_A = 25^{\circ}C$	D	2.3	W	
	T _A = 125°C	P_{D}	0.5	VV	
Operating Junction and Storage Temperature Range		T_J,T_STG	- 55 to +150	°C	

THERMAL RESISTANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Thermal Resistance – Junction to Case	R _{eJC}	3.1	°C/W	
Thermal Resistance – Junction to Ambient	$R_{\Theta JA}$	53	°C/W	

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

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ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	30			V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	$V_{GS(TH)}$	1.2	1.6	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20 V, V_{DS} = 0 V$	I _{GSS}			±100	nA
Drain-Source Leakage Current	$V_{GS}=0V,\ V_{DS}=30V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 15A$	_		4.8	6	_
(Note 3)	$V_{GS} = 4.5V, I_D = 15A$	$R_{DS(on)}$		6.7	9	mΩ
Forward Transconductance (Note 3)	$V_{DS} = 5V, I_{D} = 15A$	g _{fs}		38		S
Dynamic (Note 4)						
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 15V,$ $I_{D} = 15A$	Q_g		25.4		
Total Gate Charge	$V_{GS} = 4.5V, V_{DS} = 15V,$	Q_{g}		12.9		nC
Gate-Source Charge		Q_gs		3.8		
Gate-Drain Charge	I _D = 15A	Q_{gd}		5.7		
Input Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$	C _{iss}		1342		
Output Capacitance		C _{oss}		227		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		169		
Gate Resistance	f = 1.0MHz, open drain	R_g	0.8	2.7	5.4	Ω
Switching (Note 4)						
Turn-On Delay Time	$V_{GS} = 10V, V_{DS} = 15V,$ $I_D = 15A, R_G = 3.3\Omega,$	t _{d(on)}		7.5		
Rise Time		t _r		14.5		
Turn-Off Delay Time		t _{d(off)}		35.2		ns
Fall Time		t _f		9.6		
Source-Drain Diode						
Diode Forward Voltage (Note 3)	$V_{GS} = 0V, I_{S} = 15A$	V _{SD}			1	V
Reverse Recovery Time	I _S = 15A,	t _{rr}		8.8		ns
Reverse Recovery Charge	di/dt = 100A/μs	Q _{rr}		26		nC

Notes:

- 1. Current limited by package.
- 2. $L=0.1mH,~V_{GS}=10V,~V_{DS}=25V,~R_{G}$ = 25 $\Omega,~I_{AS}=29A,~Starting~T_{J}=25^{\circ}C$
- 3. Pulse test: Pulse Width \leq 300 μ s, duty cycle \leq 2%.
- 4. Switching time is essentially independent of operating temperature.

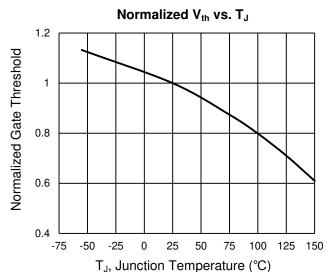
ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM060N03PQ33 RGG	PDFN33	5,000pcs / 13" Reel

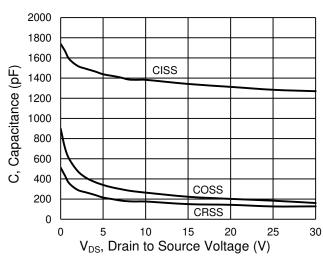


CHARACTERISTICS CURVES

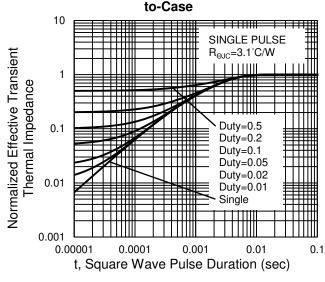
(T_A = 25°C unless otherwise noted)



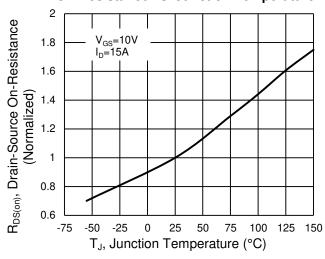
Capacitance vs. Drain-Source Voltage



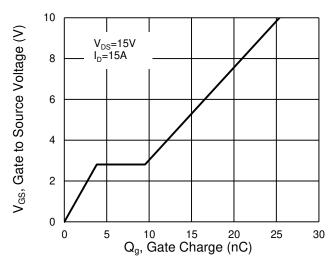
Normalized Thermal Transient Impedance, Junction-



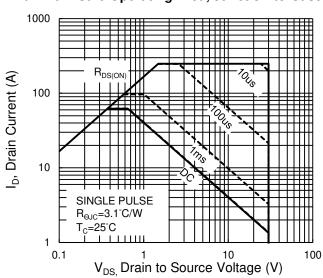
On-Resistance vs. Junction Temperature



Gate-Source Voltage vs. Gate Charge



Maximum Safe Operating Area, Junction-to-Case



Version: C1608

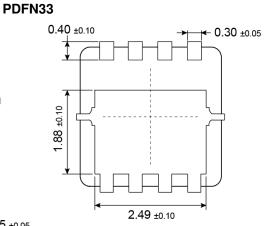
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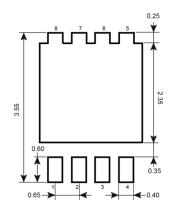
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

0.65 (REF)





SUGGESTED PAD LAYOUT (Unit: Millimeters)



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MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

 \mathbf{O} =Jan \mathbf{P} =Feb \mathbf{Q} =Mar \mathbf{R} =Apr

 $S = May \quad T = Jun \quad U = Jul \quad V = Aug$

W = Sep X = Oct Y = Nov Z = Dec

 $L = \text{Lot Code } (1 \sim 9, A \sim Z)$



Taiwan Semiconductor

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